

Change Summary

CHANGES

No.	Applicable Section	Description	Page(s)
1	Title	Change the title to read 'Phase-Shift PWM Controller'	1
2	Ordering Information	Add OZT1060GN	1
3	General Description	Add 1 st paragraph 'OZT1060 is a high...LCD.'	1
4	Functional Block Diagram Description	Add 1 st paragraph 1 st sentence 'Specific DC/DC...application'	5
5	Reference Application Circuit	Add DC/DC Reference Application Circuit	10
6	Package information	Correct 20 Pin SOIC 300mil drawing	12
7	Throughout data sheet	Miscellaneous corrections	---

REVISION HISTORY

Revision No.	Description of change	Release Date
0.95	Initial Release	1/13/2004
1.0	1. Pin Description - Modified pin description of CTIMR, DIM. 2. Electrical Characteristics - Update a) 'Nominal voltage' Min & Max limits plus Temp coefficient, b) 'Line regulation' & 'Load regulation' Typ & Max limits, c) 'Normal operating frequency' Min, Max, Typ limits plus Temp coefficient, d) 'Ramp peak' Min, Typ & Max limits, e) 'Ramp valley' Min & Max limits, f) 'Operating Frequency' Min & Max limits plus Temp coefficient, g) 'Ramp peak' & 'Ramp valley' Min & Max limits, h) 'Reference voltage at non-invereting input pin' Min & Max limits, i) 'Stand-by current' Min & Max limits, j) 'Supply current' Max limit, k) 'SST current' Min & Max limits plus Temp coefficient, l) 'SST protection release threshold' Min, Typ & Max limits, m) 'CTIMR current 1' Min & Max limits plus Temp coefficient, n) 'CTIMR current 2' Min & Max limits, o) 'PDR_A/ PDR_C' & 'NDR_B/ NDR_D' Min, Typ & Max limits, p) 'Enable' Min limit, q) 'Threshold voltage' Min & Max limits, r) 'Open-lamp threshold' Min & Max limits, s) 'BBM time between PDR & NDR' Min & Max limits plus Temp coefficient, t) 'Maximum overlap' Min, Typ & Max limits, u) 'Minimum overlap' Typ & Max limits. 3. Simplified Functional Block Diagram. 4. Modified formula in No. 4 Ignition & No. 5 Normal Operation. 5. Revise Application Circuit 6. Miscellaneous corrections.	7/29/2004
1.1	1. Footer: Add patent number 6,259,615 2. Application circuit: a.) Delete R3, R7, R6 & R11. b) Change R9 value from 45.3k to 47K	8/11/2004

Phase-Shift PWM Controller

FEATURES

- Controller for high-voltage DC/DC and DC/AC converters
- High efficiency, zero-voltage switching
- Supports wide input voltage range
- Constant operating frequency
- Built-in PWM dimming control with wide dimming range
- Soft start function
- Built-in intelligence for ignition and normal operation of CCFLs
- Built-in open-lamp protection and over-voltage protection
- Shutdown delay for input voltage brownout condition
- Built-in under-voltage lockout protection
- Toggle pin to reset the IC after shutdown
- Low stand-by power

resulting in a lower operating temperature and higher system reliability.

OZT1060 supports a wide input voltage range and provides a constant, user-defined, operating frequency, ensuring that the CCFLs operate at a fixed frequency. This eliminates interference among CCFLs and the LCD panel. Interference causes electromagnetic compatibility (EMC) problems and may create visual effects (waterfall) on LCD panels. The controller provides a phase-shift square wave output that is able to drive a full bridge power train.

OZT1060 utilizes a pulse width modulation (PWM) dimming method to achieve a wide dimming range. The IC performs the CCFL dimming function with an analog or low frequency PWM control. The PWM frequency is user-defined.

To avoid over-shoot and in-rush current to the CCFLs during ignition, a soft start function is provided for reliable CCFL operation.

ORDERING INFORMATION

Part Number	Temp Range	Package
OZT1060S	0° C to 70° C	20-pin SSOP
OZT1060SN	0° C to 70° C	20-pin SSOP, Leadfree
OZT1060G	0° C to 70° C	20-pin SOIC
OZT1060GN	0° C to 70° C	20-pin SOIC, Leadfree

The controller provides open-lamp protection and over-voltage protection, while providing an appropriate response for either open-lamp ignition or removal of a CCFL during normal operation. Intelligent open-lamp protection and over voltage protection provides design flexibility with various transformer characteristics. Open-lamp protection time is user-defined.

In addition, OZT1060 provides a shutdown delay function that will keep the inverter module in normal operation for a short period of time if the input voltage suddenly drops and subsequently resumes to a normal level. The shutdown delay time is user-defined.

OZT1060 provides under-voltage lockout protection and will disable the IC if VDDA falls below a threshold. OZT1060 will resume normal operation when VDDA exceeds the threshold.

To reset the IC, toggle the enable (ENA) pin. OZT1060 operates with a standby current of approximately 200uA.

GENERAL DESCRIPTION

OZT1060 is a high efficiency, Pulse Width Modulation (PWM) controller designed for both DC/DC and DC/AC high-voltage applications. The average current mode control is suitable for DC/DC converters where both voltage and current feedback are required, as well as for Cold Cathode Fluorescent Lamps (CCFL) backlight applications for small and large Liquid Crystal Displays (LCD).

OZT1060 operates in a zero-voltage switching mode that minimizes electromagnetic interference (EMI). In addition, OZT1060 achieves a high power-conversion efficiency

PIN DESCRIPTION

Names	Pin No.	Description
CTIMR	1	Timing capacitor to provide striking time and timing resistor to provide shutdown delay time
OVP	2	Voltage feedback
ENA	3	Enable input
SST	4	Timing capacitor to provide Soft-Start Time
VDDA	5	Supply voltage
GNDA	6	Signal ground
REF	7	Reference voltage output
RT1	8	Timing resistor to provide striking frequency
FB	9	Current sense feedback
CMP	10	Voltage control loop compensation
NDR_D	11	N-MOSFET gate drive output
PDR_C	12	P-MOSFET gate drive output
LPWM	13	Low-frequency PWM signal for dimming control
DIM	14	DC voltage input for LPWM duty cycle
LCT	15	Timing capacitor to provide LPWM frequency
PGND	16	Power MOSFET driver ground
RT	17	Timing resistor to provide striking and operating frequency
CT	18	Timing capacitor to provide striking and operating frequency
PDR_A	19	P-MOSFET gate drive output
NDR_B	20	N-MOSFET gate drive output

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

VDDA	7.0V
GNDA, PGND	+/- 0.3V
Signal inputs	-0.3V to (VDDA +0.3)V

Operating Temp.	0°C to 70°C
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Operating junction temp.	125 °C
Storage temp.	-55 °C to 150 °C

RECOMMENDED OPERATING RANGE

VDDA	4.6V to 5.5V
f _{OP} - operating frequency	40 kHz to 150kHz ⁽²⁾
Resistor connected to RT (R _{RT})	20 kΩ to 150 kΩ
Capacitor connected to CT (C _{CT})	100pF to 470pF
f _{LF} - LPWM frequency	100Hz to 500Hz
Thermal Impedance (θ _{J-A})	
- 20-pin SSOP	80°C/W
- 20-pin SOIC	105°C/W

Note ⁽¹⁾: The “Absolute Maximum Ratings” are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The “Functional Specifications” table will define the conditions for actual device operation. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

Note ⁽²⁾: The frequency of PDR_A, NDR_B, PDR_C, and NDR_D outputs pulses, f_{OP}, is half of fosc value, f_{OP}=(fosc/2).

ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Test Conditions		Limits		Unit
		VDDA=5V; Tamb=25°C;	Min	Typ	Max	
Reference Voltage						
Nominal voltage	Vref	Iload = 30μA	3.18	3.35	3.52	V
		Temp coefficient (Tamb=25°C)	-	125	-	ppm/°C
Line regulation	KL	VDDA=4.6V to 5.5V	-	2	-	mV/V
Load regulation	KV	Iload = 5 μA to 80 μA	-	2	-	mV
Operating Frequency						
Normal Operating Frequency	fop	CCT =220pF ⁽¹⁾ ; RRT =47kΩ ⁽¹⁾	61.5	63.0	65.5	kHz
		Temp coefficient (Tamb=25°C)	-	125	-	ppm/°C
Ramp peak	CT Vpeak		2.35	2.50	2.65	V
Ramp valley	CT Vvalley		1.00	1.05	1.12	V
Low Frequency Oscillator						
Operating frequency	fLF	CLCT=6.8nF(2); VDIM=1.2V	209	220	225	Hz
		Temp coefficient (Tamb=25°C)	-	470	-	ppm/°C
Ramp peak	LCT Vpeak		1.96	2.06	2.18	V
Ramp valley	LCT Vvalley		0.27	0.31	0.33	V
Duty Cycle Range	LPWM		0	-	100	%
Error Amplifier						
Reference voltage at non-inverting input pin (internal)	VADJ	VSST=0V	0.49	0.50	0.55	V
		VSST=2V	0.79	0.80	0.81	V
		VSST=4V	1.18	1.24	1.30	V
Under-Voltage Lockout						
Positive-Going Threshold Voltage			4.3	-	-	V
Negative-Going Threshold Voltage			-	-	3.2	V
Supply						
Stand-by Current	Ioff	ENA=low	-	200	300	μA
Supply Current	Ion	DIM=1.2V; LPWM=50kΩ Ca=Cb=Cc=Cd=0.5nF ⁽³⁾ CCT =220pF ⁽¹⁾ , RRT =47kΩ ⁽¹⁾ ; CLCT=6.8nF ⁽²⁾	-	3.0	4.2	mA
Soft Start						
SST current			4.5	5.5	6.2	μA
		Temp coefficient (Tamb=25°C)	-	420	-	ppm/°C
SST Protection Release Threshold			VDDA -1.25	VDDA -1.0	VDDA -0.93	V
CTIMR						
CTIMR current 1			2.0	2.5	2.9	μA
		Temp coefficient (Tamb=25°C)	-	395	-	ppm/°C
CTIMR current 2			20	30	40	μA
Protection release threshold			2.9	3.1	3.3	V

ELECTRICAL CHARACTERISTICS (CONTINUED)

Parameter	Symbol	Test Conditions		Limits		Unit
		VDDA=5V; Tamb=25°C;	Min	Typ	Max	
Output Driver Rds(on)						
PDR_A / PDR_C		Sourcing=75mA	12	25	35	Ω
NDR_B / NDR_D		Sinking=75mA	13	25	36	Ω
Enable Thresholds						
Enable			2.3	-	-	V
Disable			-	-	1.0	V
Over-Voltage Protection						
Threshold Voltage	OVP		1.95	2.00	2.20	V
Open-Lamp Protection Threshold						
Open-Lamp Threshold		CMP> open-lamp threshold causes shutdown	2.54	2.70	2.82	V
Break-Before-Make (BBM)						
BBM Time Between PDR and NDR			150	200	220	ns
		Temp coefficient (Tamb=25°C)	-	495	-	ppm/ °C
Maximum / Minimum Duty Cycle						
Maximum Overlap		Vsst = 3.75V ; Vcmp = 3.24V	91	95	-	%
Minimum Overlap		Vsst = 0.8V ; Vcmp = 3.5V	-	2.5	3.9	%

Note ⁽¹⁾

C_{CT}: capacitor from "CT" (Pin 18) to ground

R_{RT}: resistor from "RT" (Pin 17) to ground

Note ⁽²⁾

C_{LCT}: capacitor from "LCT" (Pin 15) to ground

Note ⁽³⁾

Ca: capacitor from PDR_A (Pin 19) to VDDA

Cb: capacitor from NDR_B (Pin 20) to ground

Cc: capacitor from PDR_C (Pin 12) to VDDA

Cd: capacitor from NDR_D (Pin 11) to ground

FUNCTIONAL BLOCK DIAGRAM DESCRIPTION

Specific DC/DC applications can be shown with a Reference Application Circuit in Figure 3, page 10. The following discussions will address the OZT1060 driving a DC/AC CCFL application. Refer to the Functional Block Diagram in Figure 1, page 6 and the Reference Application Circuit in Figure 2, page 9. The drive circuit consists of four outputs, PDR_A, NDR_B, PDR_C and NDR_D, (pins 19, 20, 12 and 11) respectively. The drive circuit is designed to achieve high efficiency, zero-voltage switching operation. The four power MOSFET gate output drives, PDR_A, NDR_B, PDR_C and NDR_D are designed such that switches QA/QB and QC/QD never turn-on simultaneously. The configuration prevents any shoot-through issues associated with bridge-type power conversion applications. CCFL current regulation is achieved by adjusting the overlap conduction between diagonal switches QA/QD and QB/QC. The overlap is adjusted when the power source voltage varies.

The Reference Block provides a precision reference voltage for both internal and external uses.

OZT1060 is enabled with a voltage greater than 2V applied to ENA (pin 3). A voltage of less than 1V to ENA pin will disable the controller. Toggling ENA (pin 3) from High-Low-High will reset the controller.

Soft-start circuitry provides a gradual increase in power to the drive circuit to power the CCFLs during the ignition period. The Soft-Start Time (SST) is user-defined by an external capacitor connected to SST (pin 4) coupled with an SST current source of 5.5uA.

A High Frequency Oscillator Block generates a user-defined operating frequency determined by an external capacitor (C5) and timing resistor (R9) connected to CT (pin 18) and RT (pin 17) respectively. An external resistor (R10) connected to RT1 (pin 8) in parallel with RT determines the striking frequency.

The current control loop monitors CCFL current that is sensed with a voltage at FB (pin 9). The voltage at FB (pin 9) is input to an Error Amplifier and the output, CMP (pin 10), regulates the CCFL current.

OZT1060 provides an Over-Voltage Protection (OVP) function to safely operate the CCFLs under all conditions. The OVP Block regulates the striking voltage for the CCFL during start-up. The striking time is user-defined and determined by an external capacitor connected to CTIMR (pin 1) coupled with the CTIMR current source of 2.6uA.

The Protection Block intelligently monitors and differentiates the striking condition and open-lamp condition. The open-lamp protection function disables the drive circuit if a fault condition is encountered.

A current source of 30uA coupled with an external capacitor and external resistor connected to pin 1 controls the shutdown delay time. The shutdown delay time will keep the inverter module in normal operation for a short period of time if the input voltage suddenly drops and subsequently increases to a normal level. The shutdown delay time is user-defined.

The Under-Voltage Lockout block provides a brown-out period during which the output signals are disabled while the VDDA voltage drops below a ~3.4V threshold. OZT1060 resumes normal operation once VDDA voltage reaches a voltage threshold of greater than ~4.3V.

The LPWM Generator Block provides a low frequency PWM (LPWM) function that provides wide dimming control for the CCFLs. The LPWM frequency is user-defined by connecting an external capacitor to LCT (pin 15). An analog voltage at DIM (pin 14) is compared with the LCT waveform that yields a LPWM signal to control the power delivered to the CCFLs.

FUNCTIONAL BLOCK DIAGRAM

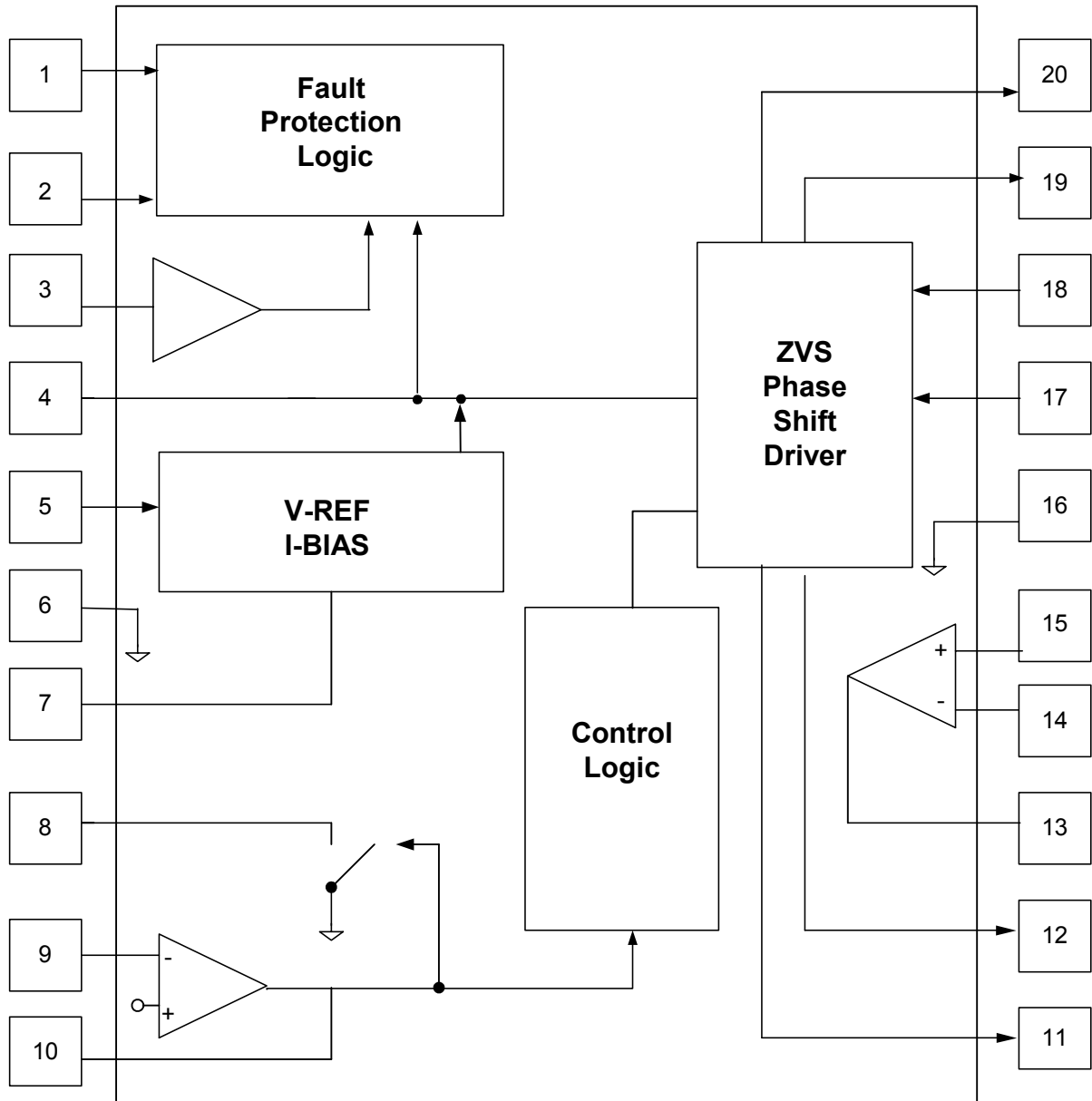


Figure 1

FUNCTIONAL INFORMATION

1. Steady-State Operation

Referring to the example schematic shown in Figure 2, page 9, OZT1060 drives a full-bridge power train where the transformer couples the energy from the power supply source to the CCFL. The switches in the bridge denoted as QA, QB, QC and QD are configured such that the transistors in each pair, QA/QB and QC/QD, are turned-on complementarily. The turn-on duration of the diagonal switches, QA/QD and QB/QC, simultaneously determines the amount of energy delivered to the transformer and subsequently to the CCFL. The current in the CCFL is sensed and regulated by adjusting the turn-on time (overlap) for both diagonal switches. This is accomplished through an error amplifier in the current feedback loop.

A voltage loop is used to regulate the output voltage for CCFL ignition and is programmable by using a capacitor divider (C8/C13).

Over Voltage Protection (OVP) limits the transformer voltage under an open-lamp condition. A soft-start circuit ensures a gradual increase in power to the CCFL. The soft-start capacitor (C9) determines the rate of rise of the voltage on the SST pin. Meanwhile, the voltage level determines the turn-on time of the diagonal switches QA/QD and QB/QC.

The output drives for the power MOSFET gates include PDR_A, NDR_B, PDR_C and NDR_D that output a complementary square pulse. The operation of the four switches is implemented with zero-voltage switching that provides a high-efficiency power conversion.

2. Enable

OZT1060 is enabled when the voltage on ENA (pin 3) is greater than 2V. A voltage of less than 1V disables the IC. When the inverter controller is disabled, it draws approximately 200uA. An under-voltage lockout protection feature is provided that will disable the IC if VDDA voltage drops below an ~3.4V threshold. The IC will resume normal operation once VDDA reaches a threshold voltage of greater than ~4.3V.

3. Soft-Start

To avoid component stresses and in-rush current to the CCFLs during ignition, a soft start function is implemented to provide reliable CCFL operation. The soft-start function is initiated when

the voltage at ENA (pin 3) is greater than 2V. The soft-start time is determined by an external capacitor (C9) connected to the SST (pin 4). At start-up, as C9 charges via a charging current, the voltage level at the capacitor controls the gradual increase in power delivered to the transformer T1.

4. Ignition

The OZT1060 provides an option of selecting a different frequency for striking the CCFLs. The striking time is user-defined and determined by an external capacitor C_{CTIMR} (C6) and external resistor R_{CTIMR} (R5) connected to CTIMR (pin 1). The approximate striking time is determined by the following equation.

$$T[\text{second}] = \frac{C_{CTIMR}[\mu\text{F}] \times (3 - (R_{CTIMR}[\text{k}\Omega] \times 0.0026))}{2.6}$$

The approximate striking frequency is determined by the following equation.

$$f_{\text{striking}}[\text{kHz}] = \frac{65 \cdot 10^4}{C_{CT}[\text{pF}] \cdot (R_{RT} // R_{RT1})[\text{k}\Omega]}$$

Note: $R_{RT} // R_{RT1}$ means R_{RT} is in parallel with R_{RT1} .

5. Normal Operation

Once the IC is enabled, the voltage at SST (pin 4) controls the rate of power delivered to the load. SST voltage increases to a level such that the CCFLs are ignited. The striking frequency is determined by external components R10, R9 and C5 connected to RT1 (pin 8), RT (pin 17) and CT (pin 18) respectively.

Once the external resistor R16 senses sufficient current, the control loop takes control and regulates the CCFL current. The normal operating frequency is determined by the combination of external resistor R9 and external capacitor C5. The operating frequency is approximated by the following equation.

$$f_{\text{op}}[\text{kHz}] = \frac{65 \cdot 10^4}{C_{CT}[\text{pF}] \cdot R_{RT}[\text{k}\Omega]}$$

6. Open Lamp Protection

If the controller encounters an open lamp, damaged lamp or lamp removal during normal operation, the control loop generates a protection signal and will immediately shutdown the controller.

OZT1060 provides a shutdown delay feature that keeps the inverter module in normal operation if the input voltage suddenly drops and subsequently recovers. The shutdown delay time is user-defined by external resistor R_{CTIMR} (R5) and external capacitor C_{CTIMR} (C6) connected to CTIMR (pin 1).

The shutdown delay time is approximated by the following equation:

$$T[\text{second}] = \frac{C_{CTIMR}[\mu\text{F}] \times (3 - (R_{CTIMR}[\text{k}\Omega] * 0.03))}{30}$$

Note: R_{CTIMR} (R5) value equal or greater than $110\text{k}\Omega$ will result in zero delay time.

Toggling ENA (pin 3) from High-Low-High resets the controller.

7. Over-Voltage Protection & Striking Time

During start-up, once the voltage at the transformer secondary reaches a programmed threshold, the control loop takes over and regulates the voltage at the transformer secondary. SST voltage at pin 4 is held constant and CTIMR is activated to provide additional time to ignite an aged CCFL. If no current is sensed after approximately 1 to 2 seconds, the controller shuts down. Toggling the ENA pin will reset the controller.

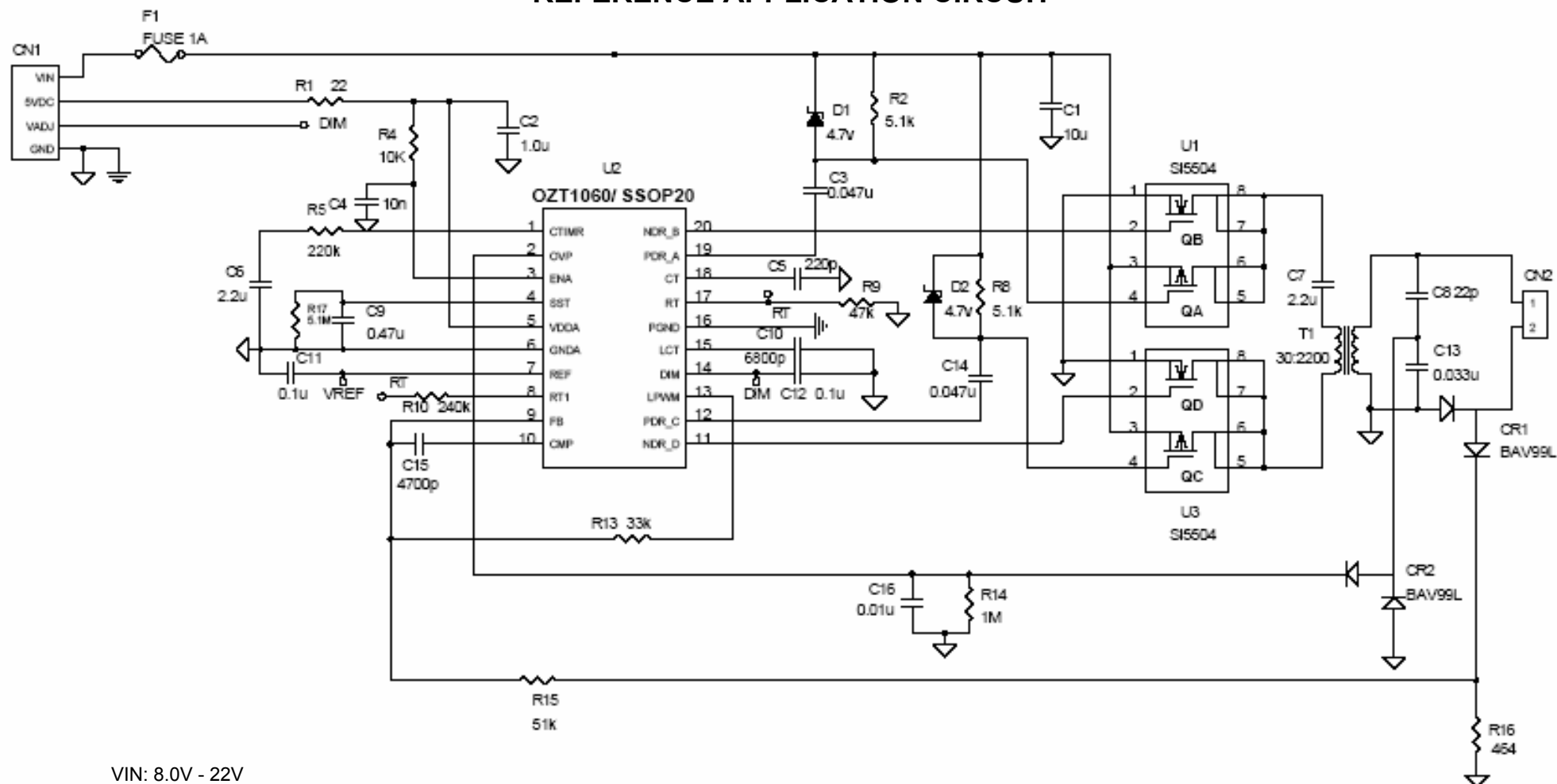
8. PWM Dimming Control

OZT1060 provides a low frequency PWM (LPWM) dimming function to perform a wide dimming range of 0% to 100%. The LPWM frequency is determined by external capacitor C10 connected to LCT (pin 15). The frequency is approximated by the following equation.

$$f_{LF}[\text{Hz}] = \frac{1496}{C_{LCT}[\text{nF}]}$$

The LPWM frequency is user-defined by the selection of external capacitor C10. An analog voltage at DIM (pin 14) is compared with the LCT waveform that yields a LPWM signal to control the power delivered to the CCFLs. The typical peak and valley of the LCT waveform is $\sim 2.06\text{V}$ and $\sim 0.31\text{V}$ respectively.

REFERENCE APPLICATION CIRCUIT



VIN: 8.0V - 22V
VADJ: 2.1V Max. Brightness; 0.6V Min. Brightness
Striking frequency: 75.1KHz
Operating frequency: 63KHz
5VDC: 4.75V - 5.25V

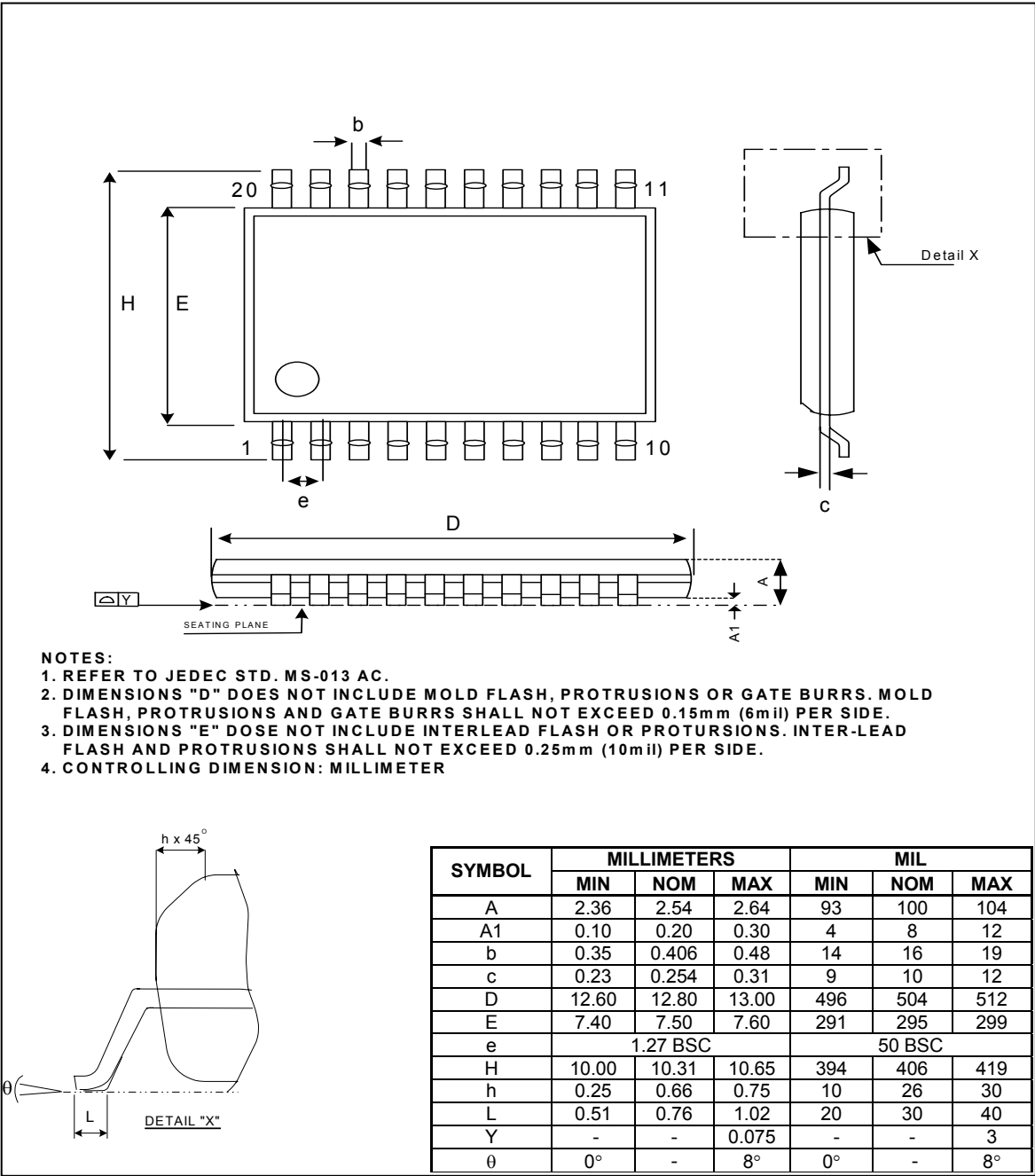
Figure 2

OZT1060



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PACKAGE INFORMATION – 20-PIN SOIC 300mil: OZT1060G



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